

## ELECTRONIC SUPPLEMENTARY INFORMATION

### Template-Free Solvothermal Preparation of ZnO Hollow Microspheres Covered with *c* Planes

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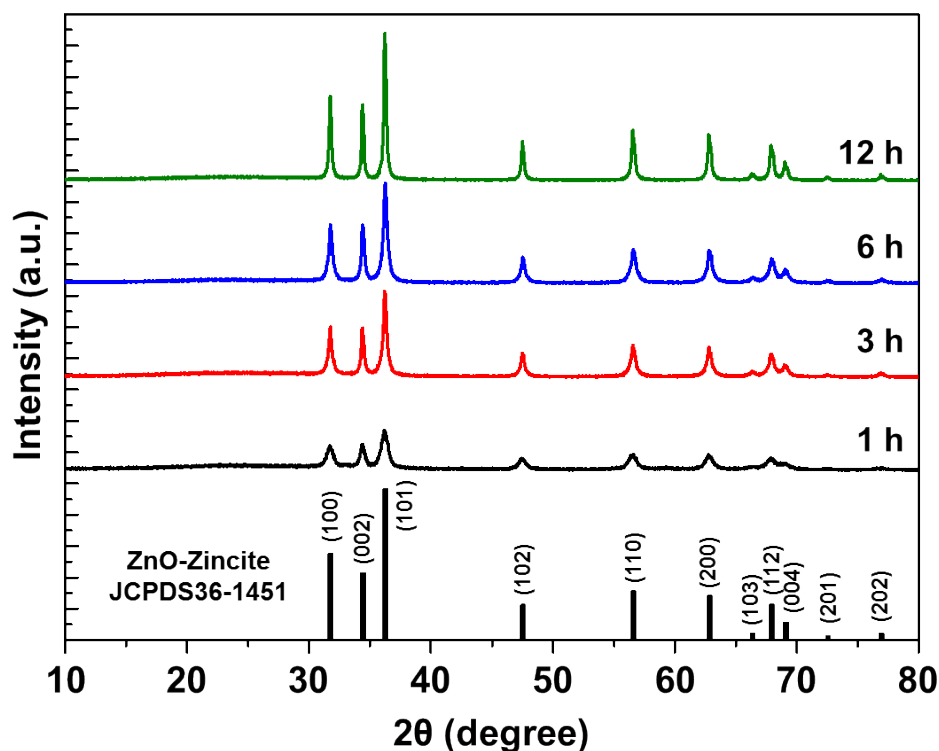


Figure S1. XRD patterns of ZnO particles prepared at 150 °C for different reaction times.

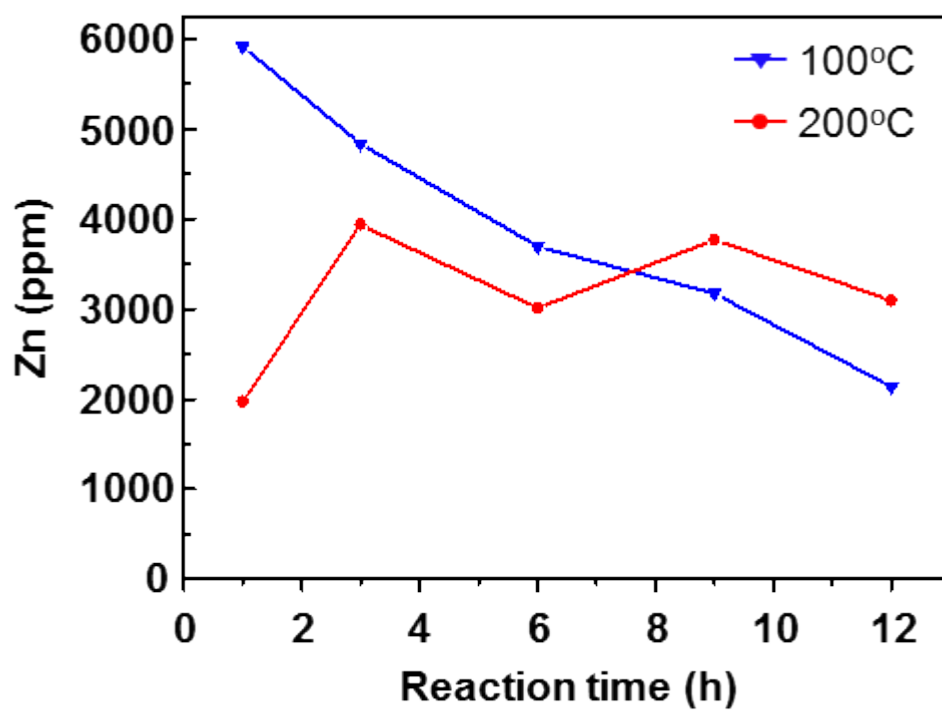


Figure S2. ICP-AES analyses of the variation of supernatant Zn concentration, after reaction at 100 and 200 °C for different reaction times.